

December 1992

Features

- High Voltage Types (20V Rating)
- CD4067BMS Single 16 Channel Multiplexer/Demultiplexer
- CD4097BMS Differential 8 Channel Multiplexer/Demultiplexer
- Low ON Resistance: 125Ω (typ) Over 15Vp-p Signal Input Range for VDD - VSS = 15V
- High OFF Resistance: Channel Leakage of ±10pA (typ) at VDD - VSS = 18V
- Matched Switch Characteristics: RON = 5Ω (typ) for VDD - VSS = 15V
- Very Low Quiescent Power Dissipation Under All Digital Control Input and Supply Conditions: 0.2μW (typ) at VDD - VSS = 10V
- Binary Address Decoding on Chip
- 5V, 10V and 15V Parametric Ratings
- 100% Tested for Quiescent Current at 20V
- Maximum Input Current of 1μA at 18V Over Full Package Temperature Range; 100nA at 18V and +25°C
- Standardized Symmetrical Output Characteristics

Applications

- Analog and Digital Multiplexing and Demultiplexing
- A/D and D/A Conversion
- Signal Gating

* When these devices are used as demultiplexers the "CHANNEL IN/OUT" terminals are the outputs and the "COMMON OUT/IN" terminals are the inputs.

Description

CD4067BMS and CD4097BMS CMOS analog multiplexers/demultiplexers* are digitally controlled analog switches having low ON Impedance, low OFF leakage current, and internal address decoding. In addition, the ON resistance is relatively constant over the full input-signal range.

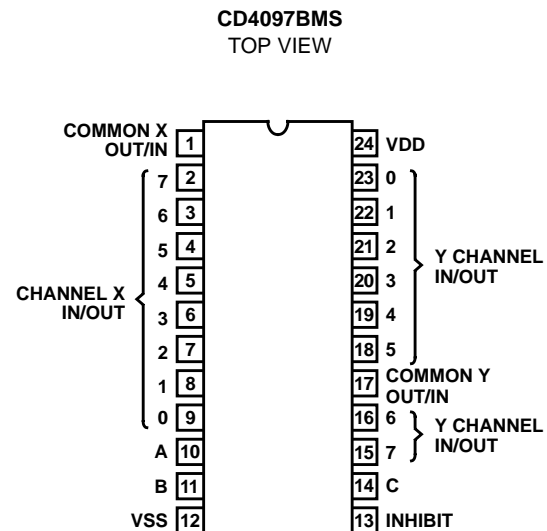
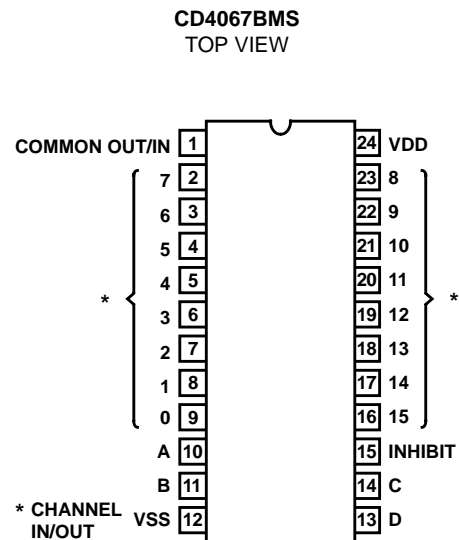
The CD4067BMS is a 16 channel multiplexer with four binary control inputs, A, B, C, D and an inhibit input, arranged so that any combination of the inputs selects one switch.

The CD4097BMS is a differential 8 channel multiplexer having three binary control inputs A, B, C and an inhibit input. The inputs permit selection of one of eight pairs of switches. A logic "1" present at the inhibit input turns all channels off.

The CD4067BMS and CD4097BMS are supplied in these 24 lead outline packages:

Braze Seal DIP	*H4V	†H6M
Frit Seal DIP	*H1Z	†HFN
Ceramic Flatpack	*H4P	†H4P
*CD4067B Only	†CD4097B	

Pinout



Specifications CD4067BMS, CD4097BMS

Absolute Maximum Ratings

DC Supply Voltage Range, (VDD) -0.5V to +20V
 (Voltage Referenced to VSS Terminals)
 Input Voltage Range, All Inputs -0.5V to VDD +0.5V
 DC Input Current, Any One Input $\pm 10\mu\text{A}$
 Operating Temperature Range -55°C to +125°C
 Package Types D, F, K, H
 Storage Temperature Range (TSTG) -65°C to +150°C
 Lead Temperature (During Soldering) +265°C
 At Distance 1/16 \pm 1/32 Inch (1.59mm \pm 0.79mm) from case for
 10s Maximum

Reliability Information

Thermal Resistance θ_{ja} θ_{jc}
 Ceramic DIP and FRIT Package 80°C/W 20°C/W
 Flatpack Package 70°C/W 20°C/W
 Maximum Package Power Dissipation (PD) at +125°C
 For TA = -55°C to +100°C (Package Type D, F, K) 500mW
 For TA = +100°C to +125°C (Package Type D, F, K) Derate
 Linearity at 12mW/°C to 200mW
 Device Dissipation per Output Transistor 100mW
 For TA = Full Package Temperature Range (All Package Types)
 Junction Temperature +175°C

TABLE 1. DC ELECTRICAL PERFORMANCE CHARACTERISTICS

PARAMETER	SYMBOL	CONDITIONS (NOTE 1)		GROUP A SUBGROUPS	TEMPERATURE	LIMITS		UNITS
						MIN	MAX	
Supply Current	IDD	VDD = 20V, VIN = VDD or GND		1	+25°C	-	10	μA
				2	+125°C	-	1000	μA
		VDD = 18V, VIN = VDD or GND		3	-55°C	-	10	μA
Input Leakage Current	IIL	VIN = VDD or GND	VDD = 20	1	+25°C	-100	-	nA
				2	+125°C	-1000	-	nA
			VDD = 18V	3	-55°C	-100	-	nA
Input Leakage Current	IIH	VIN = VDD or GND	VDD = 20	1	+25°C	-	100	nA
				2	+125°C	-	1000	nA
			VDD = 18V	3	-55°C	-	100	nA
ON-State Resistance RL = 10K Returned to VDD - VSS/2	RON	VDD = 5V VIS = VSS to VDD		1	+25°C	-	1050	Ω
				2	+125°C	-	1300	Ω
				3	-55°C	-	800	Ω
		VDD = 10V VIS = VSS to VDD		1	+25°C	-	400	Ω
				2	+125°C	-	500	Ω
				3	-55°C	-	310	Ω
		VDD = 15V VIS = VSS to VDD		1	+25°C	-	240	Ω
				2	+125°C	-	320	Ω
				3	-55°C	-	220	Ω
N Threshold Voltage	VNTH	VDD = 10V, ISS = -10 μA		1	+25°C	-2.8	-0.7	V
P Threshold Voltage	VPTH	VSS = 0V, IDD = 10 μA		1	+25°C	0.7	2.8	V
Functional (Note 4)	F	VDD = 2.8V, VIN = VDD or GND		7	+25°C	VOH > VDD/2	VOL < VDD/2	V
		VDD = 20V, VIN = VDD or GND		7	+25°C			
		VDD = 18V, VIN = VDD or GND		8A	+125°C			
		VDD = 3V, VIN = VDD or GND		8B	-55°C			
Input Voltage Low (Note 2)	VIL	VDD = 5V = VIS Thru 1K VEE = VSS		1, 2, 3	+25°C, +125°C, -55°C	-	1.5	V
Input Voltage High (Note 2)	VIH	RL = 1K to VSS ISS < 2 μA on all OFF Channels		1, 2, 3	+25°C, +125°C, -55°C	3.5	-	V
Input Voltage Low (Note 2)	VIL	VDD = 15V = VIS Thru 1K VEE = VSS		1, 2, 3	+25°C, +125°C, -55°C	-	4	V
Input Voltage High (Note 2)	VIH	RL = 1K to VSS ISS < 2 μA on all OFF Channels		1, 2, 3	+25°C, +125°C, -55°C	11	-	V

Specifications CD4067BMS, CD4097BMS

TABLE 1. DC ELECTRICAL PERFORMANCE CHARACTERISTICS

PARAMETER	SYMBOL	CONDITIONS (NOTE 1)		GROUP A SUBGROUPS	TEMPERATURE	LIMITS		UNITS
						MIN	MAX	
OFF Channel Leakage Any Channel OFF or All Channels OFF (Common OUT/IN)	IOZL	VOUT = 0V	VDD = 20V	1	+25°C	-0.1	-	μA
				2	+125°C	-1.0	-	μA
				3	-55°C	-0.1	-	μA
	IOZH	VOUT = VDD	VDD = 20V	1	+25°C	-	0.1	μA
				2	+125°C	-	1.0	μA
				3	-55°C	-	0.1	μA

- NOTES: 1. All voltages referenced to device GND, 100% testing being implemented.
 2. Go/No Go test with limits applied to inputs.
 3. For accuracy, voltage is measured differentially to VDD. Limit is 0.050V max.
 4. VDD = 2.8/3.0V, RL = 200K
 VDD = 20V/18V, RL = 10K - 25K

TABLE 2. AC ELECTRICAL PERFORMANCE CHARACTERISTICS

PARAMETER	SYMBOL	CONDITIONS	GROUP A SUBGROUPS	TEMPERATURE	LIMITS		UNITS
					MIN	MAX	
Propagation Delay (Signal In to Output)	TPHL TPLH	VDD = 5V, VIN = VDD or GND (Notes 1, 2)	9	+25°C	-	60	ns
			10, 11	+125°C, -55°C	-	81	ns
Propagation Delay Address or Inhibit to Signal Out. (Channel Turning On)	TPZH TPZL	VDD = 5V, VIN = VDD or GND (Notes 2, 3)	9	+25°C	-	650	ns
			10, 11	+125°C, -55°C	-	878	ns

- NOTES:
 1. CL = 50pF, RL = 200K, Input TR, TF < 20ns.
 2. -55°C and +125°C limits guaranteed, 100% testing being implemented.
 3. CL = 50pF, RL = 10K, Input TR, TF < 20ns.

TABLE 3. ELECTRICAL PERFORMANCE CHARACTERISTICS

PARAMETER	SYMBOL	CONDITIONS		NOTES	TEMPERATURE	LIMITS		UNITS
						MIN	MAX	
Supply Current	IDD	VDD = 5V, VIN = VDD or GND		1, 2	-55°C, +25°C	-	5	μA
					+125°C	-	150	μA
		VDD = 10V, VIN = VDD or GND		1, 2	-55°C, +25°C	-	10	μA
					+125°C	-	300	μA
		VDD = 15V, VIN = VDD or GND		1, 2	-55°C, +25°C	-	10	μA
					+125°C	-	600	μA
Input Voltage Low	VIL	VDD = VIS = 10V VEE = VSS		1, 2	+25°C, +125°C, -55°C	-	3	V
Input Voltage High	VIH	RL = 1K to VSS IIS < 2μA ON OFF Channel		1, 2	+25°C, +125°C, -55°C	+7	-	V
Propagation Delay Address or Inhibit to Signal Out. (Channel Turning On)	TPZH TPZL	VDD = 10V		1, 2, 4	+25°C	-	270	ns
		VDD = 15V		1, 2, 4	+25°C	-	190	ns
Propagation Delay Signal In to Output	TPHL TPLH	VDD = 10V	VIS = VDD or GND	1, 2, 3	+25°C	-	30	ns
		VDD = 15V			+25°C	-	20	ns

Specifications CD4067BMS, CD4097BMS

TABLE 3. ELECTRICAL PERFORMANCE CHARACTERISTICS (Continued)

PARAMETER	SYMBOL	CONDITIONS	NOTES	TEMPERATURE	LIMITS		UNITS
					MIN	MAX	
Propagation Delay Address or Inhibit to Signal Out (Channel Turning Off)	TPHZ TPLZ	VDD = 5V	1, 2, 5	+25°C	-	440	ns
		VDD = 10V	1, 2, 5	+25°C	-	180	ns
		VDD = 15V	1, 2, 5	+25°C	-	130	ns
Input Capacitance	CIN	Any Address or Inhibit	1, 2	+25°C	-	7.5	pF

NOTES:

1. All voltages referenced to device GND.
2. The parameters listed on Table 3 are controlled via design or process and are not directly tested. These parameters are characterized on initial design release and upon design changes which would affect these characteristics.
3. CL = 50pF, RL = 200K, Input TR, TF < 20ns.
4. CL = 50pF, RL = 10K, Input TR, TF < 20ns.
5. CL = 50pF, RL = 300Ω, Input TR, TF < 20ns.

TABLE 4. POST IRRADIATION ELECTRICAL PERFORMANCE CHARACTERISTICS

PARAMETER	SYMBOL	CONDITIONS	NOTES	TEMPERATURE	LIMITS		UNITS
					MIN	MAX	
Supply Current	IDD	VDD = 20V, VIN = VDD or GND	1, 4	+25°C	-	25	μA
N Threshold Voltage	VNTH	VDD = 10V, ISS = -10μA	1, 4	+25°C	-2.8	-0.2	V
N Threshold Voltage Delta	ΔVTN	VDD = 10V, ISS = -10μA	1, 4	+25°C	-	±1	V
P Threshold Voltage	VTP	VSS = 0V, IDD = 10μA	1, 4	+25°C	0.2	2.8	V
P Threshold Voltage Delta	ΔVTP	VSS = 0V, IDD = 10μA	1, 4	+25°C	-	±1	V
Functional	F	VDD = 18V, VIN = VDD or GND	1	+25°C	VOH >	VOL <	V
		VDD = 3V, VIN = VDD or GND			VDD/2	VDD/2	
Propagation Delay Time	TPHL TPLH	VDD = 5V	1, 2, 3, 4	+25°C	-	1.35 x +25°C Limit	ns

- NOTES: 1. All voltages referenced to device GND. 2. CL = 50pF, RL = 200K, Input TR, TF < 20ns. 3. See Table 2 for +25°C limit. 4. Read and Record

TABLE 5. BURN-IN AND LIFE TEST DELTA PARAMETERS +25°C

PARAMETER	SYMBOL	DELTA LIMIT
Supply Current - MSI-2	IDD	± 1.0μA
ON Resistance	RONDEL10	± 20% x Pre-Test Reading

TABLE 6. APPLICABLE SUBGROUPS

CONFORMANCE GROUP	MIL-STD-883 METHOD	GROUP A SUBGROUPS	READ AND RECORD
Initial Test (Pre Burn-In)	100% 5004	1, 7, 9	IDD, IOL5, IOH5A, RONDEL10
Interim Test 1 (Post Burn-In)	100% 5004	1, 7, 9	IDD, IOL5, IOH5A, RONDEL10
Interim Test 2 (Post Burn-In)	100% 5004	1, 7, 9	IDD, IOL5, IOH5A, RONDEL10
PDA (Note 1)	100% 5004	1, 7, 9, Deltas	
Interim Test 3 (Post Burn-In)	100% 5004	1, 7, 9	IDD, IOL5, IOH5A, RONDEL10
PDA (Note 1)	100% 5004	1, 7, 9, Deltas	
Final Test	100% 5004	2, 3, 8A, 8B, 10, 11	

Specifications CD4067BMS, CD4097BMS

TABLE 6. APPLICABLE SUBGROUPS

CONFORMANCE GROUP		MIL-STD-883 METHOD	GROUP A SUBGROUPS	READ AND RECORD
Group A		Sample 5005	1, 2, 3, 7, 8A, 8B, 9, 10, 11	
Group B	Subgroup B-5	Sample 5005	1, 2, 3, 7, 8A, 8B, 9, 10, 11, Deltas	Subgroups 1, 2, 3, 9, 10, 11
	Subgroup B-6	Sample 5005	1, 7, 9	
Group D		Sample 5005	1, 2, 3, 8A, 8B, 9	Subgroups 1, 2 3

NOTE: 1. 5% Parametric, 3% Functional; Cumulative for Static 1 and 2.

TABLE 7. TOTAL DOSE IRRADIATION

CONFORMANCE GROUPS	MIL-STD-883 METHOD	TEST		READ AND RECORD	
		PRE-IRRAD	POST-IRRAD	PRE-IRRAD	POST-IRRAD
Group E Subgroup 2	5005	1, 7, 9	Table 4	1, 9	Table 4

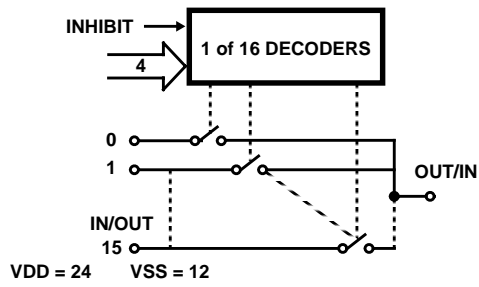
TABLE 8. BURN-IN AND IRRADIATION TEST CONNECTIONS

FUNCTION	OPEN	GROUND	VDD	9V ± -0.5V	OSCILLATOR	
					50kHz	25kHz
PART NUMBER CD4067BMS						
Static Burn-In 1 Note 1	1	2 - 23	24			
Static Burn-In 2 Note 1	1	12	2 - 11, 13 - 24			
Dynamic Burn-In Note 1	-	12, 15	24	1	2 - 9, 16 - 23	10, 11, 13, 14 (Note 3)
Irradiation Note 2	1	12	2 - 11, 13 - 24			
PART NUMBER CD4097BMS						
Static Burn-In 1 Note 1	1, 17	2 - 16, 18 - 23	24			
Static Burn-In 2 Note 1	1, 17	12	2 - 11, 13 - 16, 18 - 24			
Dynamic Burn-In Note 1	-	12, 13	24	1, 17	2 - 9, 15, 16, 18 - 23	10, 11, 14 (Note 4)
Irradiation Note 2	1, 17	12	2 - 11, 13 - 16, 18 - 24			

NOTE:

1. Each pin except VDD and GND will have a series resistor of $10K \pm 5\%$, $VDD = 18V \pm 0.5V$
2. Each pin except VDD and GND will have a series resistor of $47K \pm 5\%$; Group E, Subgroup 2, sample size is 4 dice/wafer, 0 failures, $VDD = 10V \pm 0.5V$
3. Pin 10 is at 14kHz, Pin 11 is at 7kHz, Pin 13 is at 1.7kHz, Pin 14 is at 3.5kHz
4. Pin 10 is at 14kHz, Pin 11 is at 7kHz, Pin 14 is at 3.5kHz

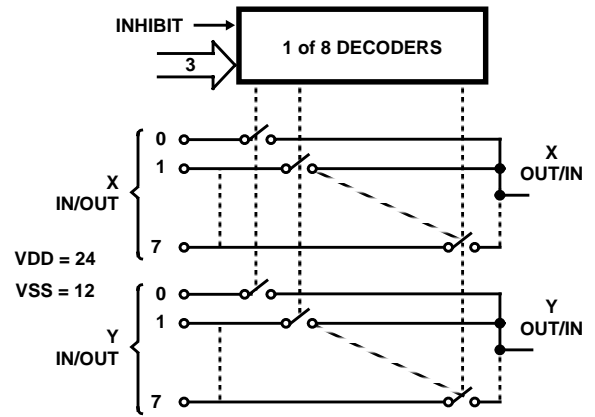
Functional Diagram



CD4067

CD4067 TRUTH TABLE

A	B	C	D	Inh	SELECTED CHANNEL
X	X	X	X	1	None
0	0	0	0	0	0
1	0	0	0	0	1
0	1	0	0	0	2
1	1	0	0	0	3
0	0	1	0	0	4
1	0	1	0	0	5
0	1	1	0	0	6
1	1	1	0	0	7
0	0	0	1	0	8
1	0	0	1	0	9
0	1	0	1	0	10
1	1	0	1	0	11
0	0	1	1	0	12
1	0	1	1	0	13
0	1	1	1	0	14
1	1	1	1	0	15



CD4097

CD4097 TRUTH TABLE

A	B	C	Inh	SELECTED CHANNEL
X	X	X	1	None
0	0	0	0	0X, 0Y
1	0	0	0	1X, 1Y
0	1	0	0	2X, 2Y
1	1	0	0	3X, 3Y
0	0	1	0	4X, 4Y
1	0	1	0	5X, 5Y
0	1	1	0	6X, 6Y
1	1	1	0	7X, 7Y

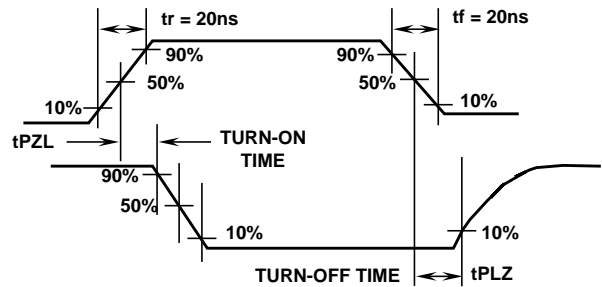


FIGURE 1. WAVEFORM CHANNEL BEING TURNED ON, OFF

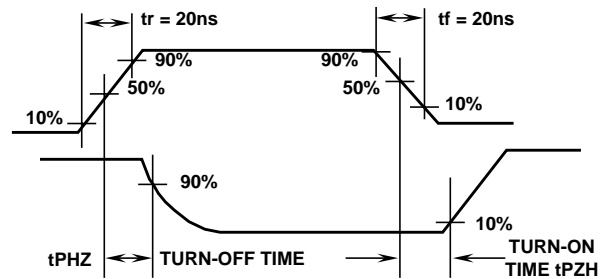


FIGURE 2. PROPAGATION DELAY WAVEFORM, CHANNEL BEING TURNED OFF, ON

CD4067BMS, CD4097BMS

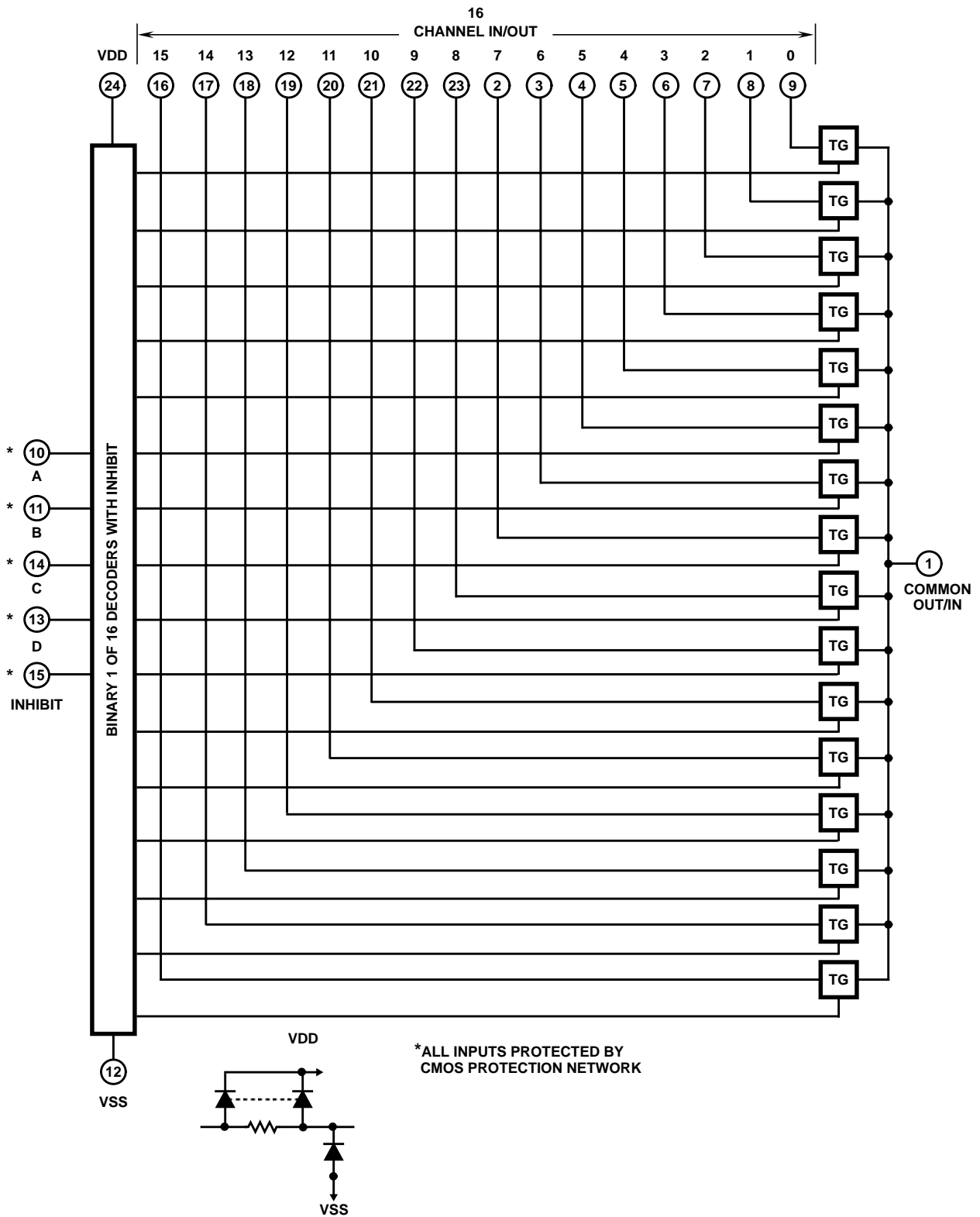
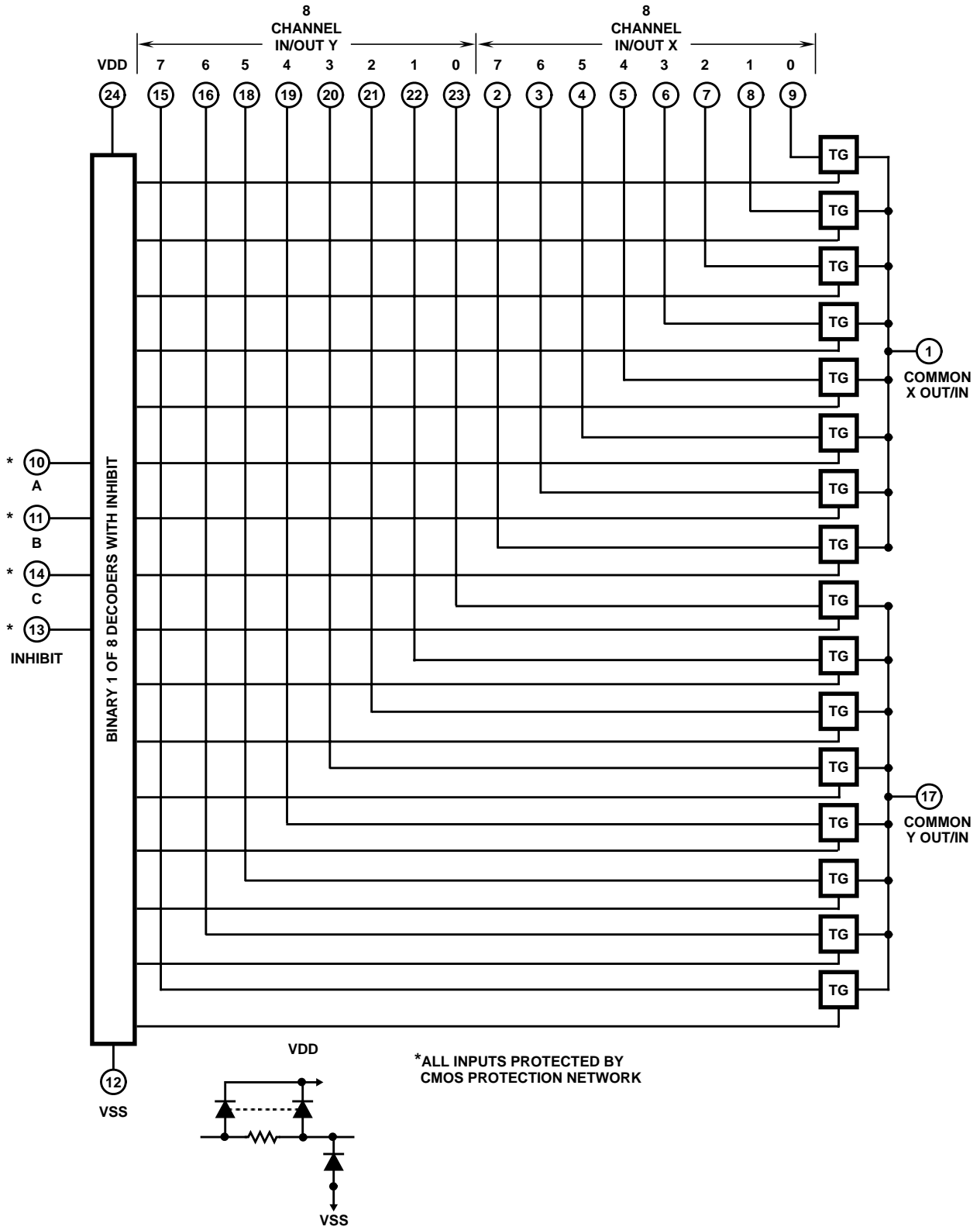


FIGURE 3. CD4067BMS LOGIC DIAGRAM

CD4067BMS, CD4097BMS



*ALL INPUTS PROTECTED BY CMOS PROTECTION NETWORK

FIGURE 4. CD4097BMS LOGIC DIAGRAM

Typical Performance Characteristics

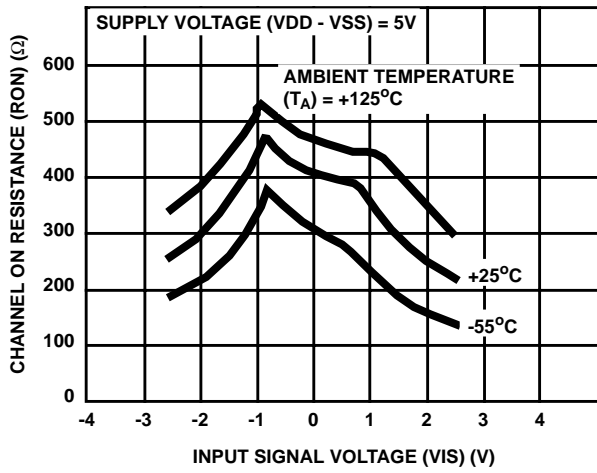


FIGURE 5. TYPICAL ON RESISTANCE vs INPUT SIGNAL VOLTAGE (ALL TYPES)

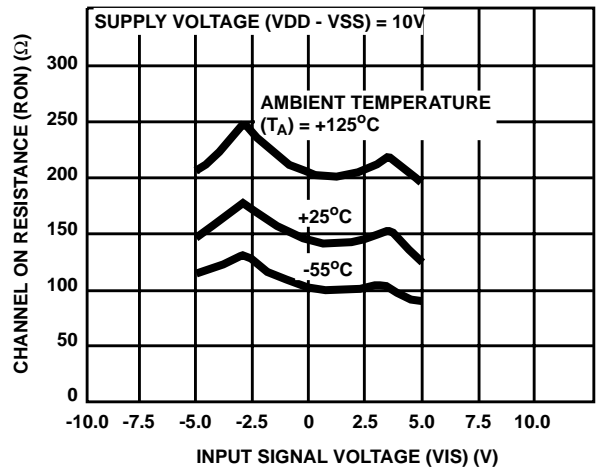


FIGURE 6. TYPICAL ON RESISTANCE vs INPUT SIGNAL VOLTAGE (ALL TYPES)

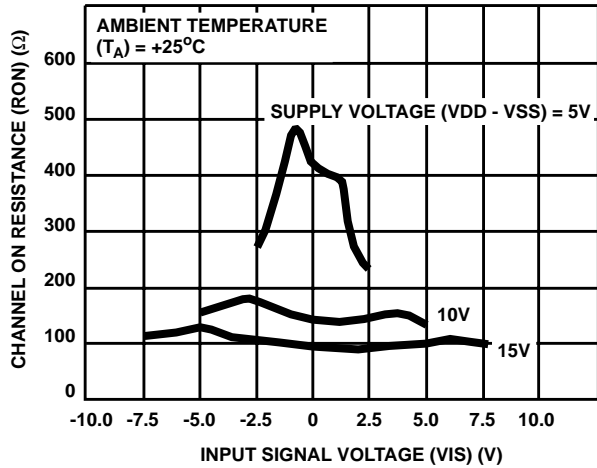


FIGURE 7. TYPICAL ON RESISTANCE vs INPUT SIGNAL VOLTAGE (ALL TYPES)

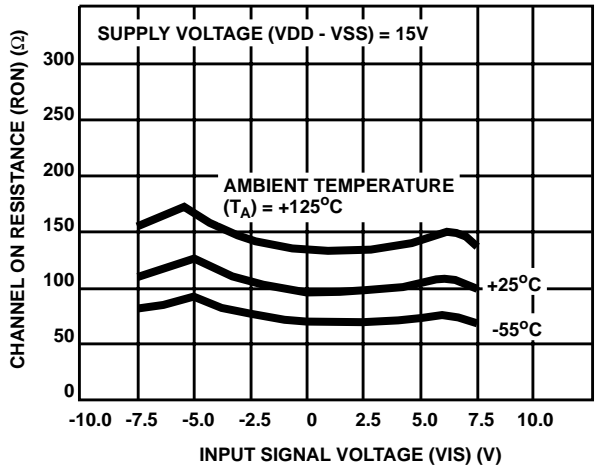


FIGURE 8. TYPICAL ON RESISTANCE vs INPUT SIGNAL VOLTAGE (ALL TYPES)